

Zero-Drift, Single-Supply, Rail-to-Rail Input/Output Operational Amplifiers

■ General Description

The HM8551, HM8552 and HM8554 are single, dual and quad amplifiers featuring rail-to-rail input and output swings, which has ultralow offset, drift and bias current. All are guaranteed to operate from +2.7 V to +5 V single supply.

With an offset voltage of only 3 μ V and drift of 20 nV/ $^{\circ}$ C, the HM8551 is perfectly suited for applications where error sources cannot be tolerated. Temperature, position and pressure sensors, medical equipment and strain gage amplifiers benefit greatly from nearly zero drift over their operating temperature range. The rail-to-rail input and output swings provided by the HM855X family make both high-side and low- side sensing easy.

The HM855X series is specified for the extended industrial/automotive (-40 $^{\circ}$ C to +125 $^{\circ}$ C) temperature range. The HM8551 single is available in 5-lead SOT and 8-lead SOP/MSOP packages. The HM8552 dual amplifier is available in 8-lead SOP/MSOP packages. The HM8554 quad is available in narrow 14-lead SOP and 14-lead TSSOP packages.

■ Applications

- Temperature Measurements
- Pressure Sensors
- Precision Current Sensing
- Electronic Scales
- Strain Gage Amplifiers
- Medical Instrumentation
- Thermocouple Amplifiers
- Handheld Test Equipment

■ Features

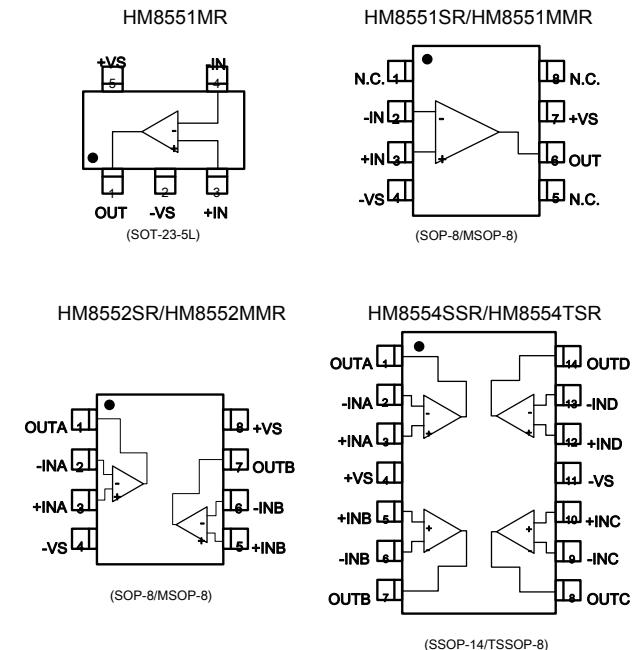
- Low Offset Voltage: 3 μ V (TYP)
- Rail-to-Rail Input and Output Swing
- 2.7V to 5.0V Single Supply Operation
- Voltage Gain: 145dB (TYP)
- PSRR: 115dB (TYP)
- CMRR: 110dB (TYP)
- Low Input Bias Currents: 130pA
- Low Supply Current: 450 μ A/Channel
- Overload Recovery Time: 0.1ms
- No External Capacitors Required
- -40 $^{\circ}$ C to +125 $^{\circ}$ C Operating Temperature Range
- Small Packaging:

HM8551 Available in Green SOT-23-5L, SOP8 and MSOP8

HM8552 Available in Green SOP8 and MSOP8

HM8554 Available in Green SOP14

■ Package



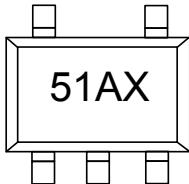
■ Ordering Information

HM855 ①②③

Designator	Symbol	Description
①		Product No.
	1	HM8551
	2	HM8552
	4	HM8554
②	—	Package
	M	SOT-23-5
	S	SOP-8
	MM	MSOP-8
	SS	SSOP-14
	TS	TSSOP-14
③	—	Device Orientation
	R	Embossed Tape: Standard Feed
	L	Embossed Tape: Reverse Feed

■ Marking

HM8551MR



HM855①②③



51---HM8551MR
 A----die code
 X----process code

HM855---HM8551 or HM8552 or HM8554
 XXXX---process code
 YYYYYY---lot code

■ Absolute Maximum Ratings

- ◊ Supply Voltage.....6V
- ◊ Input Voltage.....-VS+0.3V—+VS+0.3V
- ◊ Differential Input Voltage.....-5.0V to +5.0V
- ◊ Package Thermal Resistance @ TA = 25°C
 SOT-23-5L.....190°C/W
 MSOP-8.....216°C/W
 SOP-8.....125°C/W
 SSOP-14.....120°C/W
 TSSOP-14.....180°C/W
- ◊ Storage temperature range.....-65°C to 150°C
- ◊ Operating junction temperature.....-40°C to 125°C
- ◊ ESD Human Model.....4000V
- ◊ Lead Temperature Range (Soldering 10 sec).....260°C

■ Electrical Characteristics

(VS = +5V, VCM = +2.5V, VO = +2.5V, TA = +25°C, unless otherwise noted.)

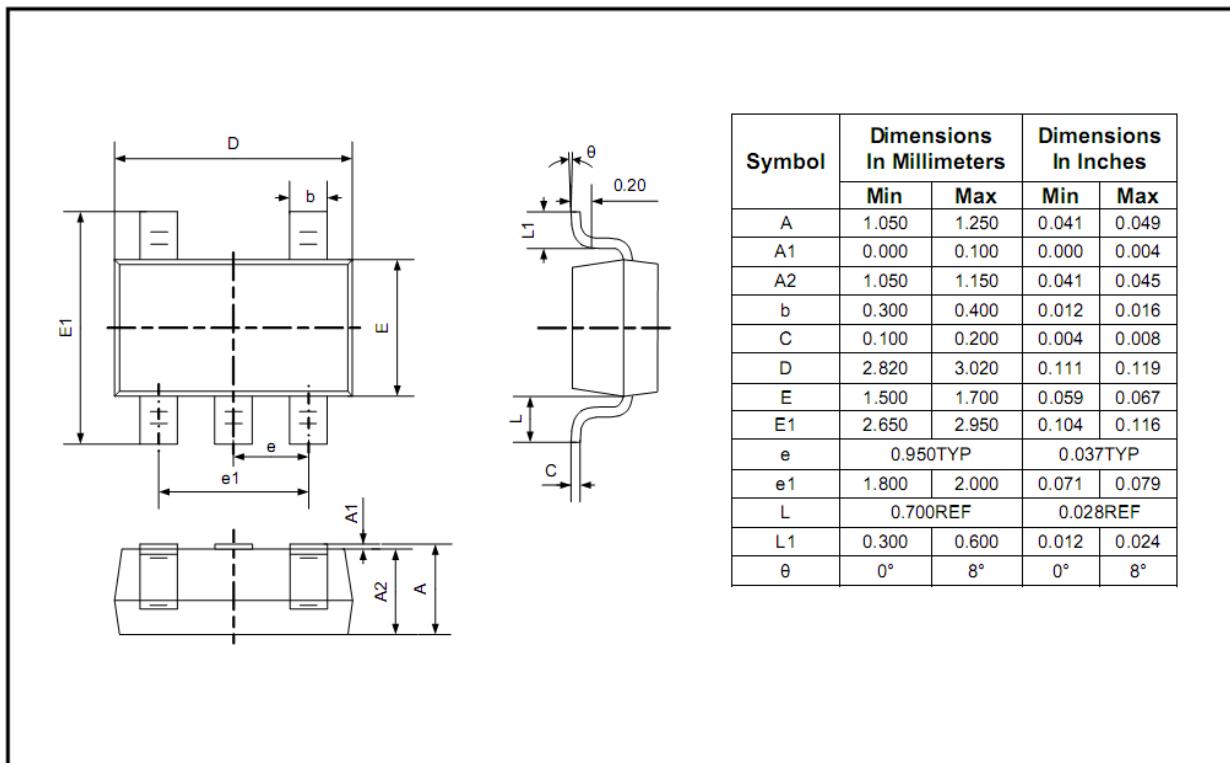
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{OS}	Input Offset Voltage		—	3	10	µV
I _B	Input Bias Current		100			pA
I _{OS}	Input Offset Current		10			pA
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 5V	110			dB
A _{VO}	Large Signal Voltage Gain	R _L = 10kΩ V _O =0.3V~4.7V	145			dB
ΔV _{OS} /ΔT	Input Offset Voltage Drift		20			nV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	RL = 100kΩ to -VS		4.998		V
		RL = 10kΩ to -VS		4.994		V
V _{OL}	Output Voltage Low	RL = 100kΩ to +VS		2		mV
		RL = 10kΩ to +VS		5		mV
I _{SC}	Short Circuit Limit	RL = 10Ω to -VS		43		mA
I _O	Output Current			30		mA
POWER SUPPLY						
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V		115		dB
I _Q	Quiescent Current	V _O = 0V, RL = 0Ω		450		µA
DYNAMIC PERFORMANCE						
GBP	Gain-Bandwidth Product	G = +100		1.44		MHz
SR	Slew Rate	RL = 10kΩ		0.84		V/µs
T _{OR}	Overload Recovery Time			0.10		ms
NOISE PERFORMANCE						
e _n p-p	Voltage Noise	0Hz to 10Hz		0.81		µVp-p
e _n	Voltage Noise Density	f = 1kHz		49		nV/√Hz

(VS = +2.7V, VCM = +1.35V, VO = +1.35V, TA = +25°C, unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{OS}	Input Offset Voltage		—	3	10	µV
I _B	Input Bias Current			75		pA
I _{OS}	Input Offset Current			5		pA
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 2.7V		110		dB
A _{VO}	Large Signal Voltage Gain	R _L = 10kΩ V _O =0.3V~2.4V		140		dB
ΔV _{OS} /ΔT	Input Offset Voltage Drift			20		nV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	RL = 100kΩ to -VS		2.699		V
		RL = 10kΩ to -VS		2.697		V
V _{OL}	Output Voltage Low	RL = 100kΩ to +VS		1		mV
		RL = 10kΩ to +VS		2		mV
I _{SC}	Short Circuit Limit	RL = 10Ω to -VS		26		mA
I _O	Output Current			10		mA
POWER SUPPLY						
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V		115		dB
I _Q	Quiescent Current	VO = 0V, RL = 0Ω		450		µA
DYNAMIC PERFORMANCE						
GBP	Gain-Bandwidth Product	G = +100		1.43		MHz
SR	Slew Rate	RL = 10kΩ		0.84		V/µs
T _{OR}	Overload Recovery Time			0.04		ms
NOISE PERFORMANCE						
e _n p-p	Voltage Noise	0Hz to 10Hz		0.90		µVp-p
e _n	Voltage Noise Density	f = 1kHz		53		nV/

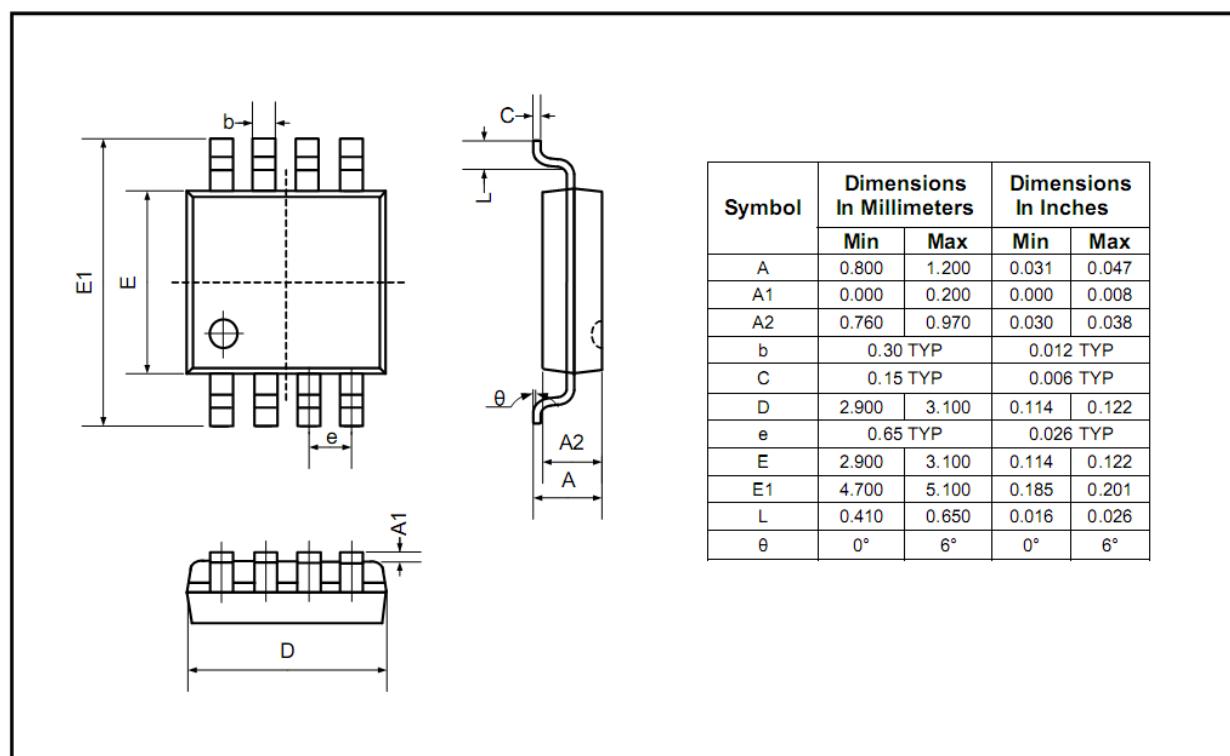
■ Package Information

SOT-23-5L



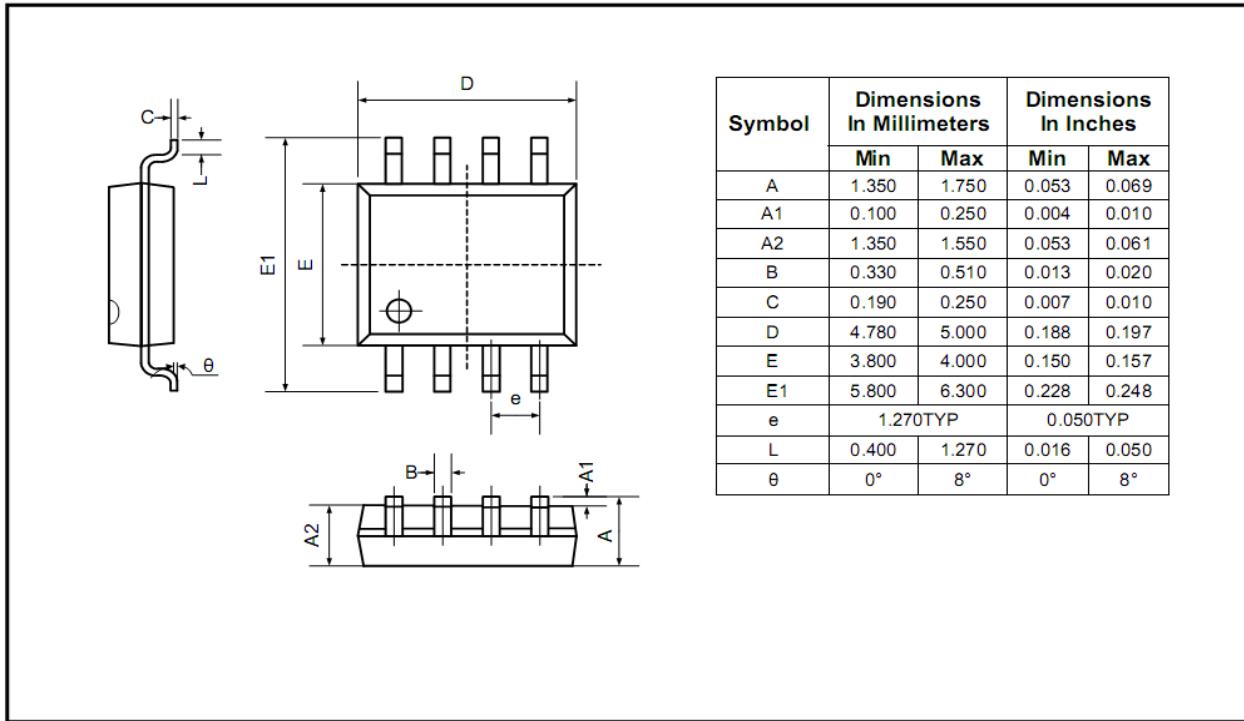
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
C	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

MSOP8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.200	0.031	0.047
A1	0.000	0.200	0.000	0.008
A2	0.760	0.970	0.030	0.038
b	0.30 TYP		0.012 TYP	
C	0.15 TYP		0.006 TYP	
D	2.900	3.100	0.114	0.122
e	0.65 TYP		0.026 TYP	
E	2.900	3.100	0.114	0.122
E1	4.700	5.100	0.185	0.201
L	0.410	0.650	0.016	0.026
θ	0°	6°	0°	6°

SOP8



SOP14

